Datasheet

SiC Schottky Barrier Diode

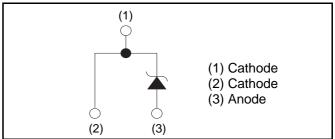
V_R	650V
I _F	15A
Q_C	23nC

●Outline TO-220AC (1) (2) (3)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

●Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

	ging opcomouncing	
	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS215AG

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (DC)		V_R	650	V
Continuous forward	d current (T _c = 134°C)	l _F	15	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		52	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	41	А
	PW=10μs square, T _j =25°C		200	Α
Repetitive peak forward current		I _{FRM}	65 ^{*1}	А
i^2 t value PW=10ms, T _j =25°C PW=10ms, T _j =150°C		ſ.2.	14	A ² s
		$\int i^2 dt$	8.4	A ² s
Total power dissipation		P_{D}	110*2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol Conditions -	Conditions	Values			Unit
Parameter		Min.	Тур.	Max.	Unit	
DC blocking voltage	V_{DC}	I _R =3.0mA	650	-	-	V
	V _F	I _F =15A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =15A,T _j =150°C	-	1.55	-	V
		I _F =15A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	3	300	μΑ
		V _R =600V,T _j =150°C	-	45	-	μΑ
		V _R =600V,T _j =175°C	-	105	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	550	-	pF
		V _R =600V,f=1MHz	-	56	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	23	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	18	-	ns

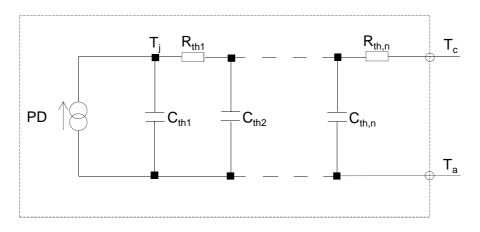
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	UTIIL
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	1.0	1.3	°C/W

●Typical Transient Thermal Characteristics

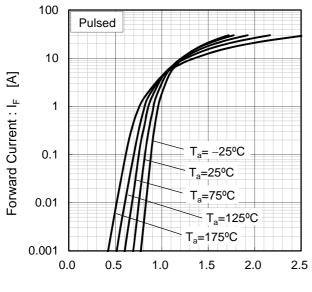
Symbol	Value	Unit
R _{th1}	3.44E-01	
R _{th2}	5.28E-01	K/W
R _{th3}	1.28E-01	

Symbol	Value	Unit
C_{th1}	2.42E-03	
C_{th2}	8.35E-03	Ws/K
C_{th3}	3.51E-01	



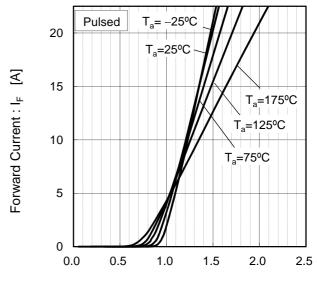
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



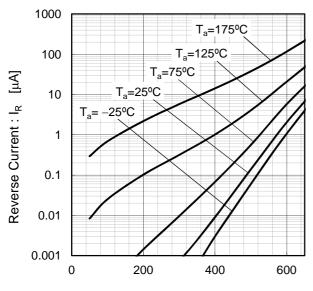
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



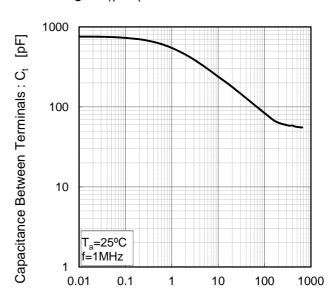
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

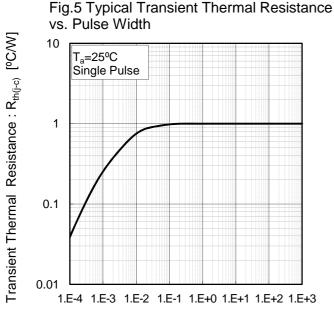
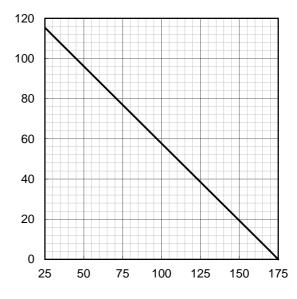


Fig.6 Power Dissipation



Pulse Width : PW [s] Case Temperature : T_c [$^{\circ}$ C]

Power Dissipation [W]

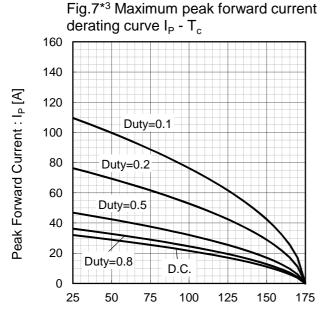
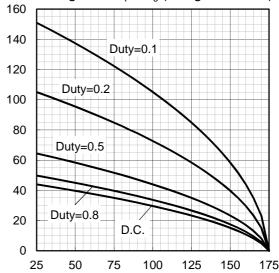


Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



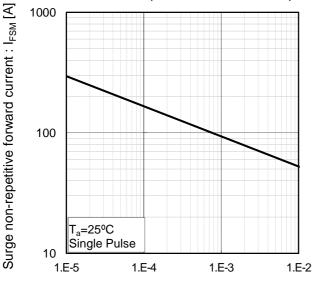
Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Case Temperature : T_c [°C] *4 Based on typ Vf, typ $R_{th(j-c)}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current: Ip [A]

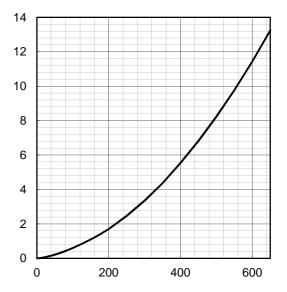
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Capacitance stored energy : $\mathsf{E}_\mathsf{C}[\mu J]$

Fig.10 Typical capacitance store energy

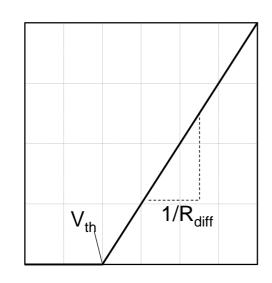


Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve

Pulse Width: PW [s]



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	2.65E-02	Ω
b ₁	6.80E-05	Ω/°C
b ₂	7.20E-07	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 30 A

Forward Current: IF

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